

Preliminary Study of Effective Copper Indium Sulfide (CuInS₂) Quantum Dots as Photo-sensitizer in Solar Cell

Nurul Syafiqah Mohamed Mustakim^a, Javad Safaei^a, Charles Ahamefula Ubani^{a,b}, Suhaila Sepeai^a, Norasikin Ahmad Ludin^a, Mohd Asri Mat Teridie^a & Mohd Adib Ibrahim^{a*}

^aSolar Energy Research Institute (SERI), Universiti Kebangsaan Malaysia, Malaysia

^bCahams Research Consultant, Nigeria

*Corresponding author: mdadib@ukm.edu.my

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ABSTRACT

Recent studies showed that quantum dots (QDs) materials such as cadmium (Cd) and lead (Pb) are commonly used as sensitizer in solar cell applications. This is mainly because they have high potential in light harvesting. However, these materials are highly toxicity and very harmful to the environment. Therefore, current investigation reports the performance of quantum dots sensitized solar cells (QDSSCs) based on non-toxicity CuInS₂ QDs by using solvothermal process. TiO₂ paste were deposited by doctor blade method on transparent conducting fluorine doped tin oxide (FTO) glass substrates. The CuInS₂ nano sized QDs were controlled by different solvothermal reaction times of 2 hours, 4 hours, 6 hours and 8 hours. In this study, the morphology, structural and optical properties of prepared TiO₂/CuInS₂ QDs thin films were investigated by using Transmission Electron Microscope (TEM), Atomic Force Microscope (AFM), X-ray Diffraction (XRD) and Ultra-Violet-Visible Near Infrared Spectrophotometer (UV-Vis). The diameter of CuInS₂ QDs was found to be increased from 3.19 nm to 8.67 nm with longer reaction time. Results showed that CuInS₂ QDs with longer reaction time produced higher conversion efficiency. Based on the experiment done, CuInS₂ QDs with 8 hours reaction time produced the best power conversion efficiency; 0.035 %. Regarding the considerable efficiencies obtained, pointed out that CuInS₂ QDs can be introduced as an effective photosensitizer for making efficient QDSSCs devices.

Keywords: Copper Indium Sulfide; Non-toxic; Quantum dots; Solar cell; Solvothermal method

INTRODUCTION

In the past few years, QDs have attracted a lot of attention due to their unique and outstanding properties (Liu et al. 2016). Basically, QDs are semiconductors material that have very small particles, between 2 and 10 nanometers in diameter (Hegazy and El-hameed 2014) (Kouhnavard et al. 2014). QDs absorb and emit exact colours at specific wavelengths that correspond to their particle size. In general, larger QDs emit red light, while smaller QDs emit blue light, with other colours appearing between red and blue light. This phenomenon of colour changes shows that the variation of QDs particle size have certain optoelectronic properties and differ in their band gap energy (Yi 2013; Badawi et al. 2014). Band gap is the energy required for electrons to move and enter the excited state. Theoretically, small-sized QDs have larger band gap and require the same or higher energy than their band gap to enter excited state. Size tuning, energy levels and emission wavelengths of QDs make them extremely useful for some optoelectronic applications including photovoltaic cells (Kamat 2013) (Chang et al. 2013) (Hod and Zaban 2014),

medical imaging (Wu et al. 2014), and sensors (Li et al. 2015) (Mozafari and Moztarzadeh 2011).

Basically, QDSSC consist of three important components which includes a photoelectrode sensitized with QDs, an electrolyte with a redox couple, and a counter electrode, as shown in Figure 1 (Mohamed Mustakim et al. 2018). Interestingly, QDs material have received considerable attention in the development of solar cell technology due to the effects of quantum confinement following the reduction in Bohr radius. The radius of Bohr's radius is the distance in the electron-hole pair which is different for each QDs material. QDs with smaller size than the Bohr radius are referred as strong quantum confinement effect, while QDs with larger size than Bohr radius are considered to be weak quantum confinement effect.

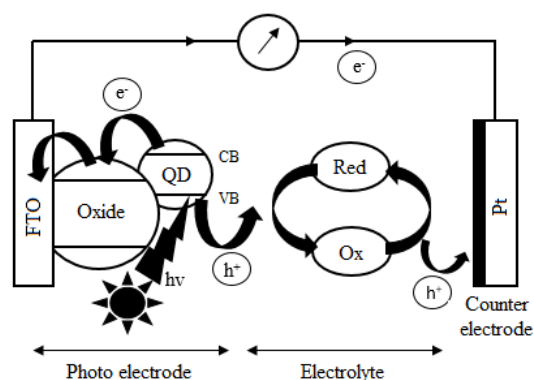


FIGURE 1. Operating principle of a typical QDSSC

As mentioned earlier, the electronic properties of QDs are determined by the size and shape that make them unique to the technology of today (Kamat 2013). In addition, photo stability and high absorption coefficients of QDs material can enhance the overall efficiency of solar cells devices. Multiple exciton generation (MEG) phenomenon is also a highly desirable feature of QDs especially in photovoltaic applications (Jun, Careem, and Arof 2013). The low cost of fabrication and production costs are also the benefits and advantages of QDSSCs.

Semiconductors such as cadmium sulphide (CdS), cadmium selenide (CdSe) and lead sulphide (PbS) have become the most popular options to be used to investigate the operating principles of QDSSCs. However, these materials are very toxicity that is seriously harmful to the environment (Z. A. Peng and Peng 2001). To overcome this issue, the development of eco-friendly QDs is very important for clean and safe QDSSCs future. CuInS₂ is a I-II-VI semiconductor material with direct energy gap of 1.5 eV (bulk) which is well matched with the full solar spectrum (Tell, Shay, and Kasper 1971) (Nanu, Schoonman, and Goossens 2005). It has many favorable features such as low cost, non-toxicity, high absorption coefficient and stable performance (Zhou et al. 2012). Theoretically, as the Bohr exciton radius of CuInS₂ is 4.1 nm, the quantum confinement effects can be observed in the nanoparticle up to size of about 8 nm (Kolny-Olesiak and Weller 2013). By controlling the sizes of CuInS₂ nanoparticles, their energy gap can be controlled as well as the absorption that can be tuned almost in the whole visible region of the solar spectrum, up to the near infrared.

Typically, larger particle size can lead to a narrower gap and the absorption edge gradually red-shifted to the higher wavelength (Liu et al. 2016) (Z. Peng et al. 2014). In general, the absorption spectrum of CuInS₂ does not show sharp peaks, but rather shows shoulder peaks. This could be attributed to the intrinsic nature of CuInS₂ itself or due to the size, shape or composition of the material in the sample studied. There are few methods can be

used to synthesize the CuInS₂ QDs such as chemical bath deposition (CBD), solvothermal, successive ionic layer adsorption and reaction (SILAR), sol gel and more (Ward 2016).

To the best knowledge, this is the first investigation of QDSSCs performance with the effect of CuInS₂ QDs as sensitizer using Ag₂S as the passivation layers. Therefore, the main purpose of the current study is to explore the influence of different reaction times of solvothermal technique on the morphology, optical and electrical properties of nanostructured CuInS₂ QDs as an effective photosensitizer in solar cell. From this study, the optimum performance of environment friendly CuInS₂ QDs sensitizer can be used for further investigation on the effect of Ag₂S passivation layers towards the performance of CuInS₂ QDs based solar cells.

METHODOLOGY

Materials

TiO₂ P25 powder (99.5%; Sigma Aldrich), Acetylacethone (99%; Sigma Aldrich), Triton X-100 (Sigma Aldrich), Copper (II) Acetate monohydrate (99%; Merck), Indium Acetate (99.99%; Sigma Aldrich), Octadecylamine (90%; Merck), Thiourea (99%; Sigma Aldrich), Iodolyte AN-50 (Sigma Aldrich), ethanol, and acetone.

Characterization techniques

Morphology analysis was done using TEM (Philips model CM12) and Roughness measurements were carried out using AFM (Nanosoft Easyscan model). Structural analysis was done using XRD (Bruker AXS Germany model D8) with Cu-K_α radiation of wavelength, 1.5406 nm. Optical absorption studies were carried out with UV-Vis spectrophotometer (Perkin Elmer model Lambda 35). Illuminated J-V characteristics of the cells were measured with the help of Keithley source measure unit and the cells were illuminated using a xenon lamp with an intensity 100 mW/cm².

Preparation of TiO₂ photoelectrode

The Fluorine doped tin oxide (FTO) coated glass was used as a substrate in this experiment. The substrates were cleaned with 1:1:1 volume ratio of acetone, ethanol, and deionized water (DI water) and finally cleaned ultrasonically for 30 minutes. The TiO₂ thin films were prepared by using similar procedures by Feng et al. (2009). Briefly, 0.5 g of TiO₂ P25 powder was dispersed in 5 mL ethanol. The dispersion was grinded for several minutes followed by an addition of 0.05 mL acetyl acetone. 0.05 mL Triton 100-X was added into the mixture to facilitate the spreading of the paste on the substrate, since this substance has the ability to reduce surface

tension, resulting in even spreading and reducing the formation of cracks (Badawi et al. 2015). Then, the prepared TiO₂ paste were spread onto cleaned FTO glass using the Doctor Blade method. Lastly, the glass substrate sintered at 450 °C for 30 minutes.

Preparation of CuInS₂ QDs

CuInS₂ QDs samples were prepared using modified solvothermal method by Yue et al. (2014). At room temperature, 0.05 mmol Cu (Ac)₂·H₂O was dispersed in 50 mL of absolute ethanol and stirred vigorously until a blue solution appeared. Then, 0.05 mmol In (Ac)₃ was added into the blue solution followed by dispersion of 0.60 mmol octadecylamine. The mixture solution was treated ultrasonically for several minutes, resulting in a sapphire colored dispersion. Addition of 0.20 mmol of CS(NH₂)₂ into the dispersion resulting a brown colored dispersion. The final brown dispersion was then transferred into a 40 mL capacity (~80%) of Teflon lined stainless steel autoclave and was heated up to 160°C for particular reaction times (t=2h, 4h, 6h and 8h). The autoclave was cooled down naturally to room temperature. Finally, the product was centrifuged (10,000 rpm, 8 minutes) and washed with absolute ethanol for 6 times. The product was then dried under N₂ environment at 60°C for 3 hours to other measurements.

Preparation of TiO₂/ CuInS₂ QDs thin films

The TiO₂ photo anode was place at an angle against the wall of the Teflon liner with the conductive side facing down. The prepared CuInS₂ precursor was transferred into an autoclave and was heated up to 160°C for different reaction times (t=2h, 4h, 6h and 8h). The autoclave was then cooled down naturally to room temperature. Finally, TiO₂/ CuInS₂ QDs thin films were rinsed by ethanol then dried at 60°C under N₂ environment for 3 hours.

RESULTS AND DISCUSSION

Morphological properties

CuInS₂ nanoparticles were synthesized at temperature 160°C with different solvothermal reaction times. The prepared CuInS₂ affirmed by TEM images as shown in Figure 2 and the QDs size were determined using TEM measurement. From the result, the CuInS₂ could be called as QDs since the nanoparticles are smaller than 10 nm (Kouhnavard et al. 2014). The CuInS₂ QDs diameter are increasing from ±3.19 nm to ±8.67 nm with longer reaction time of 2 hours to 8 hours, respectively, as stated in Table 1. As observed, the CuInS₂ QDs are quasi-spherical and it aggregates to form QDs rich domains by the individual QDs particles.

TABLE 1. The physical properties of diameter of CuInS₂ QDs with different solvothermal reaction times

Samples	Diameter [nm]	Roughness [nm]
CuInS ₂ 2h	±3.19	6.82
CuInS ₂ 4h	±5.88	12.63
CuInS ₂ 6h	±6.45	17.80
CuInS ₂ 8h	±8.67	16.61

The root mean square (RMS) analysis has been carried out using AFM to characterize the surface roughness of TiO₂/ CuInS₂ QDs thin films. From Figure 3, it is noticeable that the value of RMS increases from 6.82 nm to 17.80 nm with longer reaction time of 2 hours to 6 hours, respectively, as stated in Table 1. However, the RMS of the thin film shows a relatively smoother surface when it reaches 8 hours reaction. This could be attributed to the growth of CuInS₂ that have larger particles size than other samples, effecting the roughness reduction (A.Al-Khafaji et al. 2016).

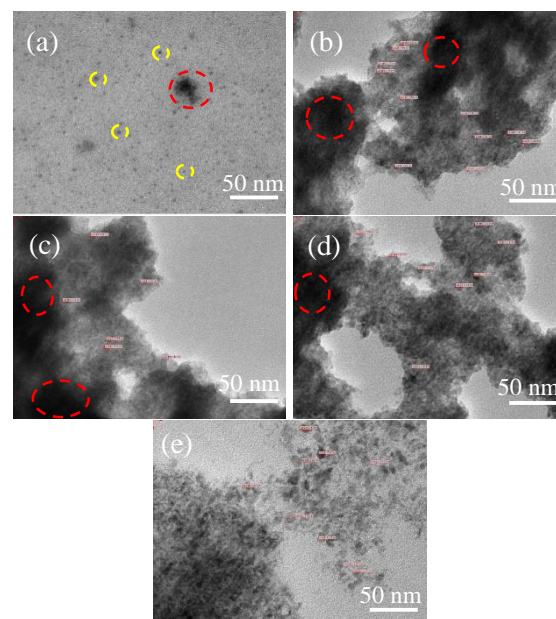


FIGURE 2. TEM images of CuInS₂ QDs with different solvothermal reaction times (a - b) 2 hours (c) 4 hours (d) 6 hours and (e) 8 hours; the yellow dashed lines identify the quasi-spherical individual QDs, while the red dashed lines identify the QDs rich domains

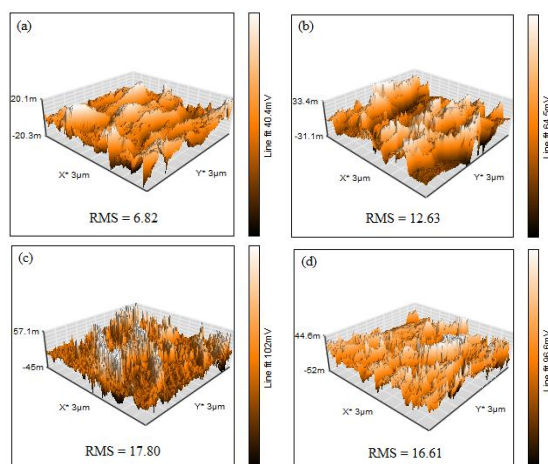


FIGURE 3. AFM images of CuInS₂ QDs with different solvothermal reaction times (a) 2 hours (b) 4 hours (c) 6 hours and (d) 8 hours

Structural properties

XRD analysis were carried out to further identify the phase composition and phase structure of prepared CuInS₂ QDs. Figure 4 displays the X-ray diffraction patterns that consists of three major peaks at 27.9°, 46.3° and 54.9° which in good agreement with crystal faces (112), (204) or (220) and (116) or (312)

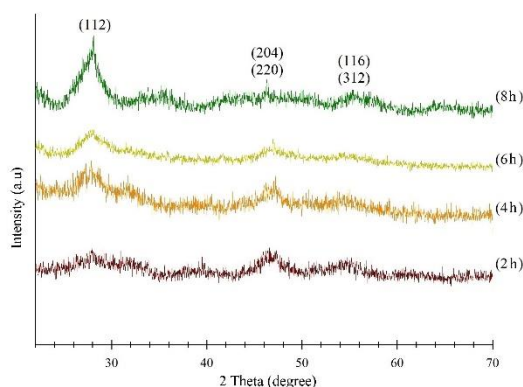


FIGURE 4. XRD spectra of CuInS₂ QDs with different solvothermal reaction times

of tetragonal CuInS₂ structure (PDF 03-065-2732). These peaks are just relatively broad which indicating small crystalline CuInS₂ particles. The crystallite size of CuInS₂ QDs was estimated to be approximately 3.69 nm, 5.64 nm, 6.19 nm, and 7.52 nm with different reaction times of 2 hours, 4 hours, 6 hours, and 8 hours, respectively, by Scherrer's equation (1). The values obtained is consistent with that observed in TEM images.

TABLE 2. The calculated crystallite size CuInS₂ QDs with different solvothermal reaction times using Scherrer's equation

Sample	Position 2θ [deg.]	FWHM [deg.]	Crystallite size [nm]
CuInS ₂ _2h	27.945	2.435	3.693
CuInS ₂ _4h	27.858	1.595	5.641
CuInS ₂ _6h	28.121	1.454	6.189
CuInS ₂ _8h	28.115	1.198	7.522

$$d = \frac{k\lambda}{\beta \cos \theta} \quad (1)$$

From the calculation, k is the shape constant (0.9), λ is the wavelength of the X-ray (0.15406 nm), β is the FWHM in radians and θ is the Bragg's angle in degrees. It is observed that there is an increment of crystallite size with longer reaction times as stated in Table 2.

Optical properties

From the absorption spectra, the light harvesting range of CuInS₂ QDs covers the whole visible spectrum and could extends to NIR region with long wavelength direction typically up to 900 nm (Yue et al. 2013). Therefore, the energy gap can be tuned between 3.3 eV and 1.7 eV. Figure 5 shows an enhancement in the optical absorbance and slightly red shifted at the absorption edge as the reaction time extended. This is obviously because of the increase in QDs particle size that would lead in the increased absorbance thus influencing the energy gap.

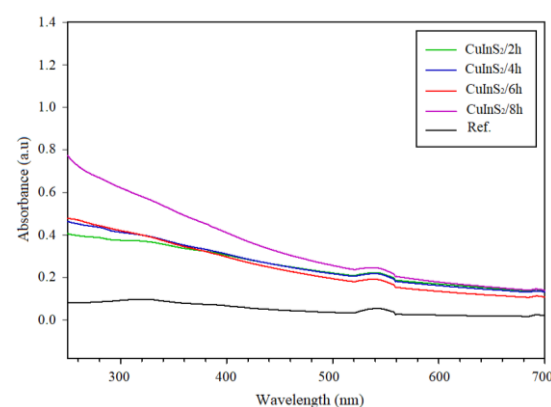


FIGURE 5. UV-VIS absorption spectra of CuInS₂ QDs with various reaction times

The energy gap of prepared CuInS₂ QDs was estimated using Tauc plot. As stated in Table 3, the energy gap for prepared CuInS₂ QDs is between 2.16 eV and 2.02 eV which are found to gradually

narrower with bigger size of QDs. This can be attributed to the QDs effect (Yue et al. 2014). In other words, larger CuInS₂ QDs with smaller energy gap helps for better absorbance, thus contributing to better and stronger light harvesting ability.

TABLE 3. Determination of band gap energy of CuInS₂ QDs at different solvothermal reaction times

Samples	Bandgap energy[eV]
CuInS ₂ 2h	2.16
CuInS ₂ 4h	2.14
CuInS ₂ 6h	2.10
CuInS ₂ 8h	2.02

Electrical properties

The photocurrent density-voltage (J-V) curves were measured under the irradiation (E) of the simulated sunlight (100 mW/cm²) to confirm the influence of different solvothermal reaction times on the photovoltaic performance, as shown Figure 6. To undergo the J-V test, the QDSSCs were fabricated as a sandwich type cell with active area (A_C) of 0.25 cm².

The TiO₂/CuInS₂ thin film was used as the photo anodes and platinum as the counter electrodes by using a thin transparent surlyn ring to inject the commercial iodine-based electrolyte (Iodolyte AN-50). Four different sets (t = 2h, 4h, 6h, 8h) of sandwiched-type solar cell were prepared to determine the device efficiency. The following equations (2) and (3) express conversion efficiency:

$$P_{max} = FF * V_{oc} * I_{sc} \quad (2)$$

$$\eta = \frac{P_{max}}{E * A_c} \quad (3)$$

TABLE 4. The conversion efficiency of CuInS₂ QDs with different solvothermal reaction times

Sample	V _{oc} (V)	I _{sc} (A)	FF (%)	P _{max} (W)	η (%)
CuInS ₂ 2h	0.158	0.030	24	2.80 x 10 ⁻⁷	0.001
CuInS ₂ 4h	0.277	0.051	25	8.90 x 10 ⁻⁷	0.004
CuInS ₂ 6h	0.305	0.181	33	4.56 x 10 ⁻⁶	0.018
CuInS ₂ 8h	0.374	0.249	37	8.63 x 10 ⁻⁶	0.035

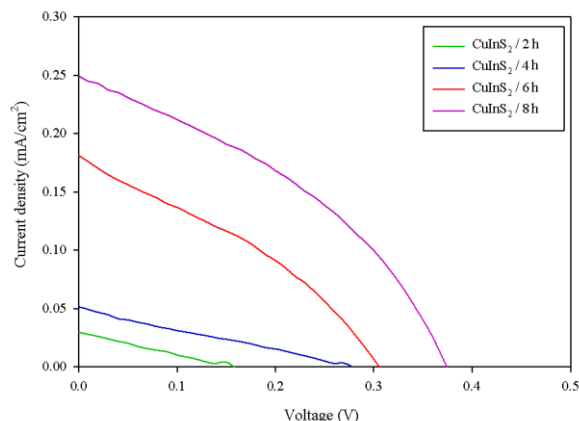


FIGURE 6. J-V curves of CuInS₂ based QDSSCs with different solvothermal reaction times

Based on these curves, the power conversion efficiency of the samples gradually increases with longer solvothermal reaction time, as listed in Table 4. The result shows the best efficiency of 0.035% with 8 hours reaction time. As can be seen that the value of short circuit current (I_{sc}) was significantly improved from 0.030 mA/cm² to 0.249 mA/cm² as the reaction time was prolonged from 2 hours to 8 hours. However, it should be noticed that the power conversion efficiency of CuInS₂ based QDSSCs present in our study is still low. This may be due to the limitation of the lattice mismatch between TiO₂ and CuInS₂ QDs and high surface state density that exist in the heterostructure of the layers which could lead in a high rate of interface recombination (Zhou et al. 2012). Therefore, a study on the band alignment of TiO₂ and CuInS₂ QDs should be conducted for better QDSSCs performance.

CONCLUSION

From the study, CuInS₂ QDs ranged of ± 3.19 nm to ± 8.67 nm has been successfully prepared with different solvothermal reaction times. The effect of reaction times on the photovoltaic performance of CuInS₂ based QDSSCs was investigated. From XRD result, there are peaks at 27.9°, 46.3° and 54.9° of tetragonal CuInS₂ structure. The broad peaks of this material indicating small crystallite size which corresponding to the CuInS₂ size obtained from TEM analysis. According to UV-VIS result, there is a small red shift of absorption edge as well as an enhancement in the optical absorbance. The energy gap of CuInS₂ QDs can also be determined which resulting in narrower gap with increased absorbance. Lastly, the efficiency of the solar cells keeps increasing as the reaction time increased. The objective of this study was achieved by obtaining the highest conversion efficiency of 0.035% when the reaction time increased up to 8 hours. Therefore, the 8 hours CuInS₂ QDs should be used for further investigation on the effect of Ag₂S passivation layer towards the CuInS₂ QDs based solar cell performance.

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